NSN 5961-01-411-4507

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-411-4507 **Inclosure Material:** Metal **Overall Length:** Between 0.240 inches and 0.260 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.370 inches **Internal Configuration:** Junction contact-darlington connected Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-39 **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 collector to base voltage, dc and 60.0 collector to emitter voltage, dc and 5.0 emitter to base voltage, instantaneous **Current Rating Per Characteristic:** Between 50.00 milliamperes source cutoff current and 4.00 amperes source cutoff current and 6.00 amperes zero-gate-voltage source current blank **Power Rating Per Characteristic:** 25.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Test Data Document:** 30003-2041as992 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No